

# 2SA836

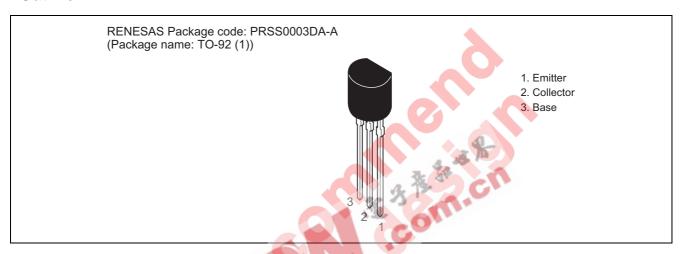
# Silicon PNP Epitaxial

REJ03G0629-0200 (Previous ADE-208-316) Rev.2.00 Aug.10.2005

### **Application**

Low frequency low noise amplifier

#### **Outline**



# **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Collector to base voltage	V <sub>CBO</sub>	<b>–</b> 55	V
Collector to emitter voltage	$V_{\sf CEO}$	<b>–</b> 55	V
Emitter to base voltage	V <sub>EBO</sub>	<b>-</b> 5	V
Collector current	Ic	-100	mA
Emitter current	I <sub>E</sub>	100	mA
Collector power dissipation	Pc	200	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

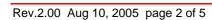
# **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

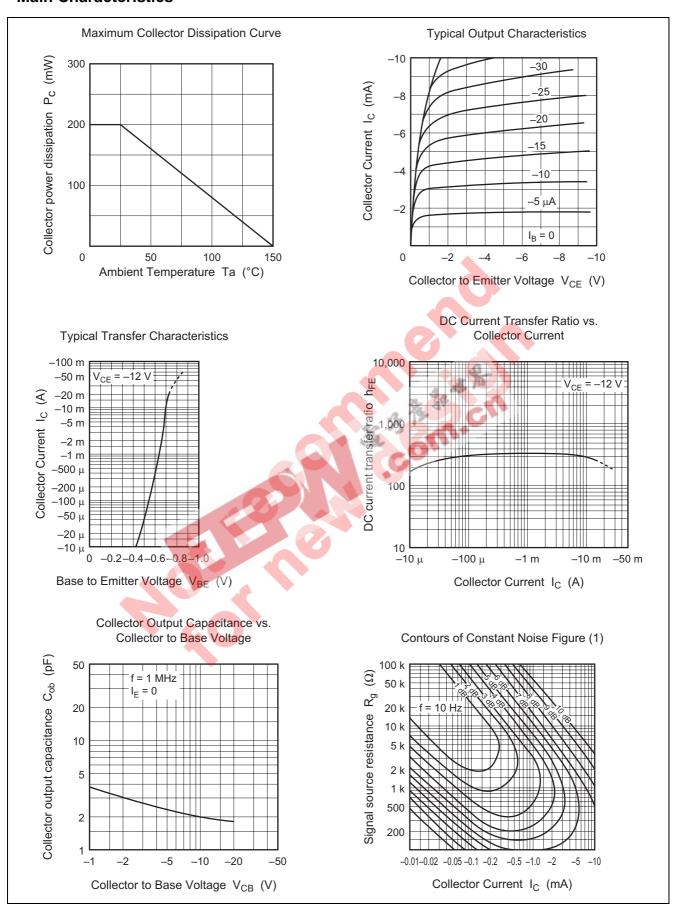
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	-55	_	_	V	$I_C = -10 \ \mu A, \ I_E = 0$
Collector to emitter breakdown	V <sub>(BR)CEO</sub>	-55	_	_	V	$I_C = -1 \text{ mA}, R_{BE} = \infty$
voltage						
Emitter to base breakdown voltage	$V_{(BR)EBO}$	<b>-</b> 5		_	<b>V</b>	$I_E = -10 \mu A, I_C = 0$
Collector cutoff current	I <sub>CBO</sub>	_	_	-100	nA	$V_{CB} = -18 \text{ V}, I_E = 0$
Emitter cutoff current	I <sub>EBO</sub>	_	_	-50	nA	$V_{EB} = -2 \text{ V}, I_C = 0$
DC current transfer ratio	h <sub>FE</sub> *1	160	_	500		$V_{CE} = -12 \text{ V}, I_{C} = -2 \text{ mA}$
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	-0.1	-0.5	V	$I_C = -10 \text{ mA}, I_B = -1 \text{ mA}$
Base to emitter voltage	$V_{BE}$	_	-0.66	-0.75	V	$V_{CE} = -12 \text{ V}, I_{C} = -2 \text{ mA}$
Gain bandwidth product	f⊤	_	200	_	MHz	$V_{CE} = -12 \text{ V}, I_E = -2 \text{ mA}$
Collector output capacitance	Cob	_	2.0	_	pF	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1MHz$
Noise figure	NF	_	1	5	dB	$V_{CE} = -6 \text{ V}, \qquad f = 10 \text{ Hz}$
		_	0.5	1	dB	$I_C = -0.1 \text{mA}, \qquad f = 1 \text{ kHz}$
						$R_g = 10 \text{ k}\Omega$

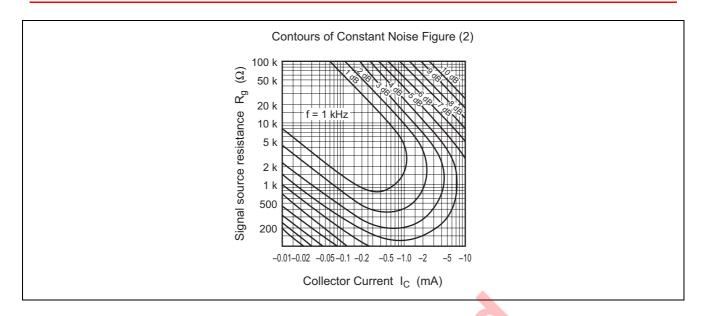
Note: 1. The 2SA836 is grouped by h<sub>FE</sub> as follows.

С	D
160 to 320	250 to 500



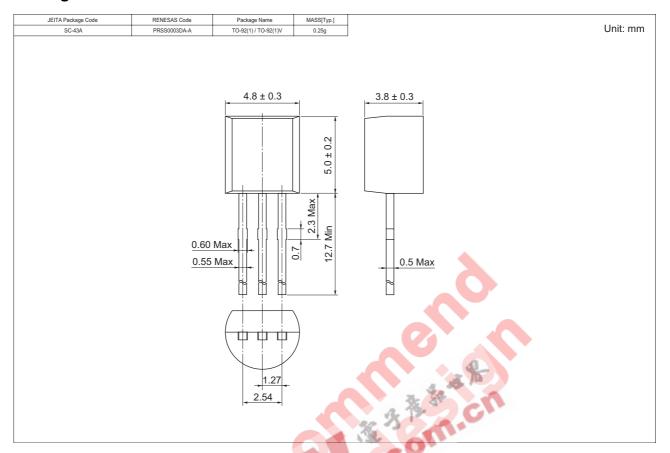
#### **Main Characteristics**







#### **Package Dimensions**



## **Ordering Information**

Part Name	Quantity	Shipping Container
2SA836CTZ	2500	Hold Box, Radial Taping
2SA836DTZ		

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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